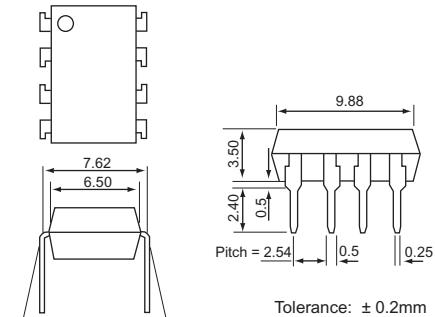


Features

1. High speed response t_{PHL} , t_{PLH}
(Max. 0.8uS at $R_L = 1.9\text{kohms}$)
2. High common mode rejection voltage.
(CMR: TYP. 1kV/uS)
3. Standard dual-in-line package.
4. Available package types: DIP(shown)/ SMD/ H (Page: 148).

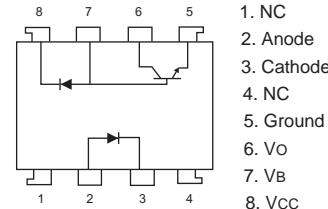
Part Numbering System: Page 2. **Part Marking System:** Page 3.

Outside Dimension: Unit (mm)



Applications

1. Computers, measuring instruments, control equipment.
2. High speed line receivers, high speed logic.
3. Telephone sets.
4. Signal transmission between circuits of different potentials and impedances.



(Ta=25°C)

Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Input	IF	25	mA
	IFM	1	A
	VR	5	V
	PD	45	mW
Output	Vcc & Vo	-0.5 to +15	V
	VEBO	5	V
	Io, IOP	8, 16	mA
	IB	5	mA
Power dissipation	PO	100	mW
Isolation voltage 1 minute ²	Viso	2500	Vrms
Operating temperature	Topr	-55 to +100	°C
Storage temperature	Tstg	-55 to +125	°C
Soldering temperature 10 second ³	Tsol	260	°C

1. Pulse width <=1uS, 300 pulse/sec. Peak forward current, 50mA, 50% duty cycle, Pulse width 1mS, Decrease at the rate of 1.6mA/°C if the external temperature is 70°C or more.
2. 40 to 60% RH, AC for 1 minute.
3. For 10 seconds.



Electro-optical Characteristics

(Ta = 0 to 70°C unless otherwise specified)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Current transfer ratio ¹	CTR(1)	Ta = 25°C, If = 16mA Vo = 0.4V, Vcc = 4.5V	19	40	-	%
	CTR(2)	If = 16mA, Vo = 0.5V, Vcc = 4.5V	15	43	-	%
Logic (0) output voltage	VOL	² Vcc = 4.5V, If = 16mA	-	0.1	0.4	V
Logic (1) output current	Ioh(1)	Ta = 25°C, Io = 0 Vo = Vcc = 5.5V	-	3.0	500	nA
	Ioh(2)	Ta = 25°C, Io = 0 Vo = Vcc = 15	-	0.01	1.0	uA
	Ioh(3)	Vcc = Vo = 15V, Io = 0	-	-	50	uA
Logic (0) supply current	Iccl	If = 16mA Vo = open, Vcc = 15V	-	200	-	uA
Logic (1) supply current	Icch(1)	Ta = 25°C, Io = 0 Vf = open, Vcc = 15V	-	0.02	1.0	uA
	Icch(2)	Io = 0 Vo = open, Vcc = 15V	-	-	2.0	uA
Input forward voltage	Vf	Ta = 25°C, If = 16mA	-	1.7	1.95	V
Input forward voltage temperature coefficient	ΔVf / ΔTa	If = 16mA	-	-1.9	-	mV/ °C
Input reverse voltage	BVR	Ta = 25°C, Ir = 10uA	5.0	-	-	V
Input capacitance	CIN	Vf = 0, f = 1MHz	-	60	-	pF
Leak current (input-output) ³	II-0	Ta = 25°C, 45%RH VI-0 = 3kVDC, t = 5s	-	-	1.0	uA
Isolation resistance (input-output) ³	Ri-0	VI-0 = 500VDC	-	10 ¹²	-	Ω
Capacitance (input-output) ³	Ci-0	F = 1MHz	-	0.6	-	pF
Transistor current amplification factor	hFE	Vo = 5V, Io = 3mA	-	70	-	

1. Current transfer ratio is the ratio of input current and output current expressed in %.
2. IO = 2.4mA
3. Measured as 2-pin element (Short 1, 2, 3, 4 and 5, 6, 7, 8).

Switching Characteristics

(Ta = 25°C, Vcc = 5V, If = 16mA)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Propagation delay time ^{1,4} Output (1) → (0)	tPHL	R _L = 1.9kohms	-	0.3	0.8	uS
Propagation delay time ^{1,4} Output (0) → (1)	tPLH	R _L = 1.9kohms	-	0.3	0.8	uS
Instantaneous common mode rejection voltage ^{2,5} Output (1)	CMH	If = 0, V _{CM} = 10V _{p-p}	-	1000	-	V/uS
Instantaneous common mode rejection voltage ^{2,5} Output (0)	CML	If = 16mA, V _{CM} = 10V _{p-p}	-	-1000	-	V/uS
Bandwidth ³	BW	R _L = 100ohms	-	2.0	-	MHz

1. R = 1.9kohms is equivalent to one LSSTL and 5.6kohms pull-up resistor.
2. Instantaneous common mode rejection voltage "output(1)" represents a common voltage variation that can hold the output above(1) level (Vo > 2.0V). Instantaneous common mode rejection voltage "output (0)" represents a common voltage variation that can hold the output above (0) level (Vo < 0.8V).
3. Bandwidth represents a point where AC input goes down by 3dB.
4. Tset Circuit Propagation Delay Time.

5. Tset Circuit for Instantaneous Common Mode Rejection Voltage

